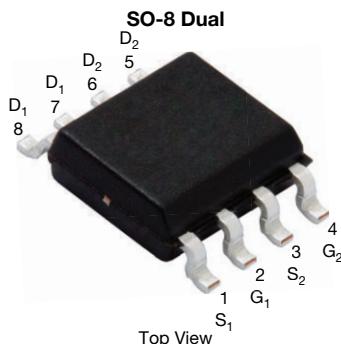


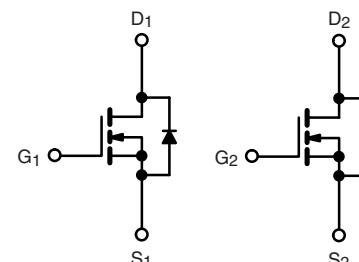
Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET® Power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE


N-Channel MOSFET N-Channel MOSFET

| PRODUCT SUMMARY | |
|-----------------------------------------------|--------|
| V_{DS} (V) | 40 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = 10$ V | 0.0135 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = 4.5$ V | 0.0148 |
| I_D (A) | 8 |
| Configuration | Dual |

| ORDERING INFORMATION | |
|---------------------------------|----------------------------------------------------------------------------------------------------------------------------|
| Package | SO-8 |
| Lead (Pb)-free and halogen-free | SQ4284EY (for detailed order number please see www.vishay.com/doc?79771) |

| ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted) | | | |
|-------------------------------------------------------------------|----------------|---------------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Drain-source voltage | V_{DS} | 40 | V |
| Gate-source voltage | V_{GS} | ± 20 | |
| Continuous drain current | I_D | 8 | A |
| $T_C = 125$ °C | | 7.4 | |
| Continuous source current (diode conduction) | I_S | 3.5 | |
| Pulsed drain current ^a | I_{DM} | 32 | |
| Single pulse avalanche current | I_{AS} | 48 | |
| Single pulse avalanche energy | E_{AS} | 115 | mJ |
| Maximum power dissipation ^a | P_D | 3.9 | W |
| $T_C = 125$ °C | | 1.3 | |
| Operating junction and storage temperature range | T_J, T_{stg} | - 55 to + 175 | °C |

| THERMAL RESISTANCE RATINGS | | | |
|----------------------------|------------|-------|------|
| PARAMETER | SYMBOL | LIMIT | UNIT |
| Junction-to-ambient | R_{thJA} | 120 | °C/W |
| Junction-to-foot (drain) | R_{thJF} | 38 | |

Notes

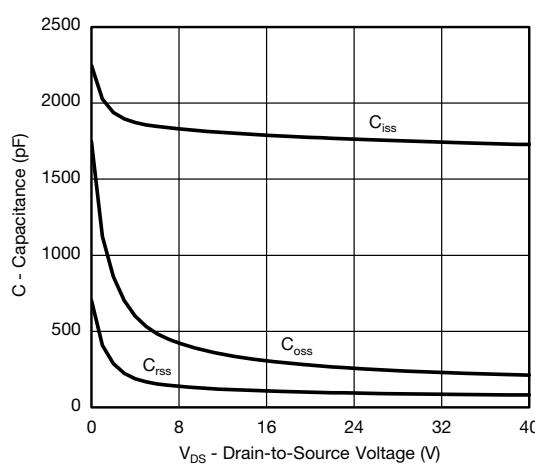
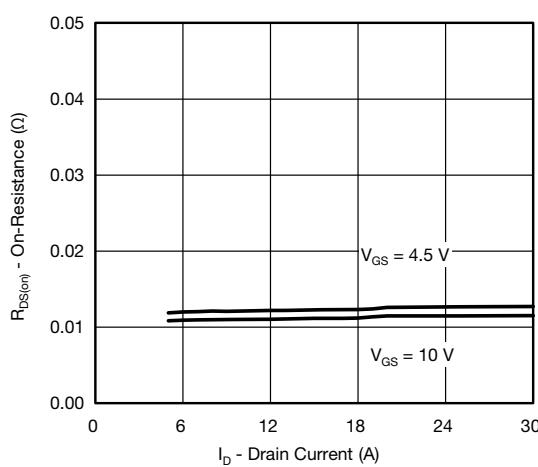
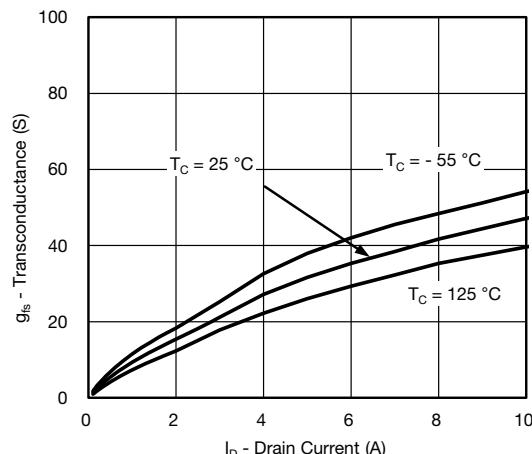
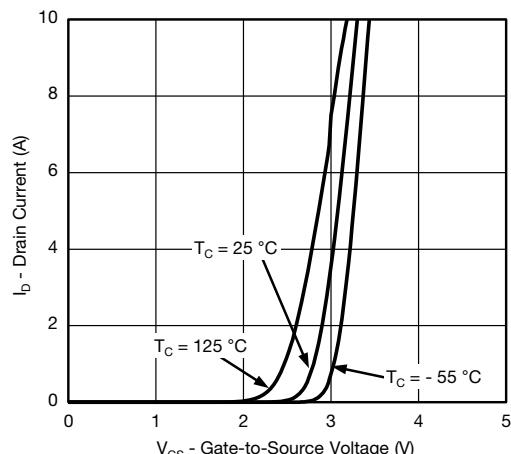
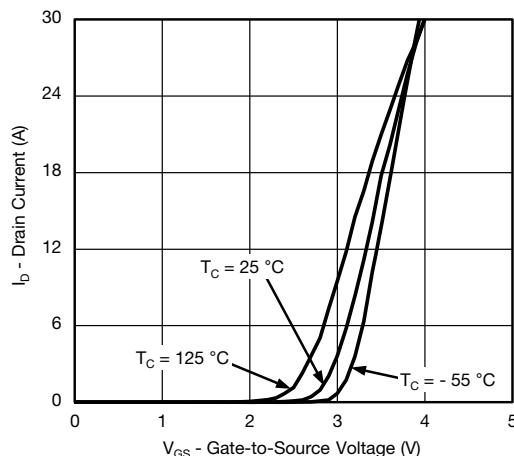
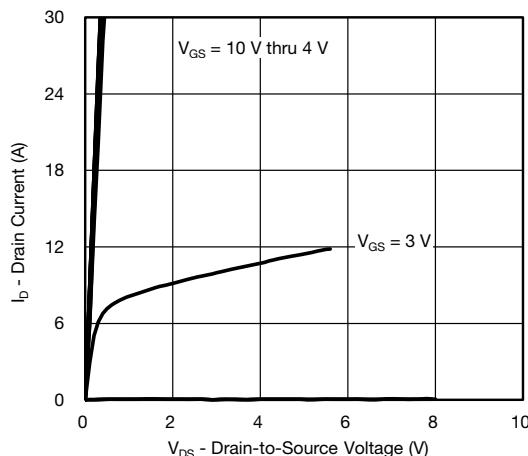
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR-4 material)

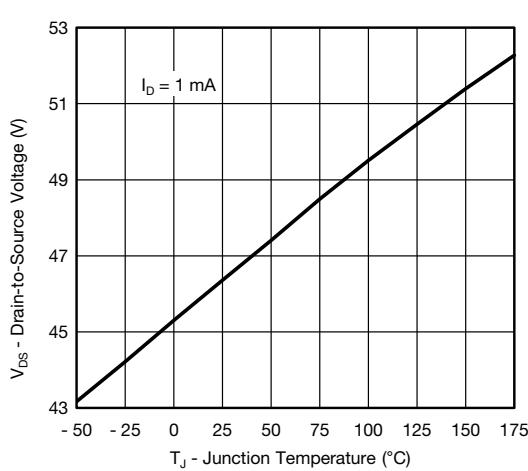
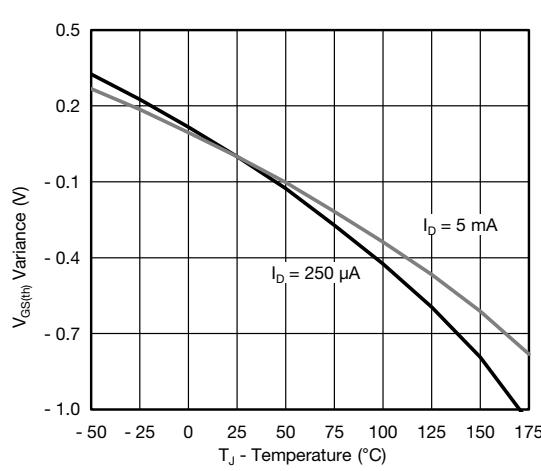
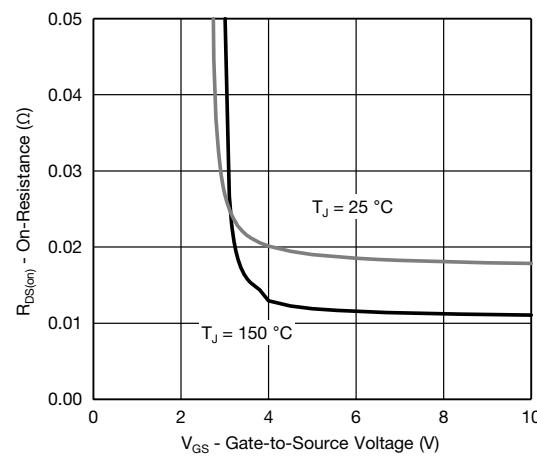
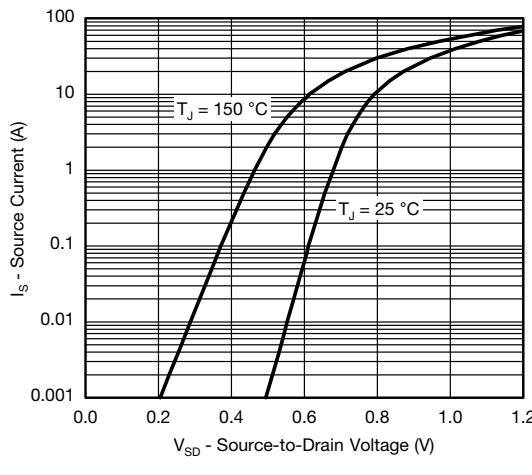
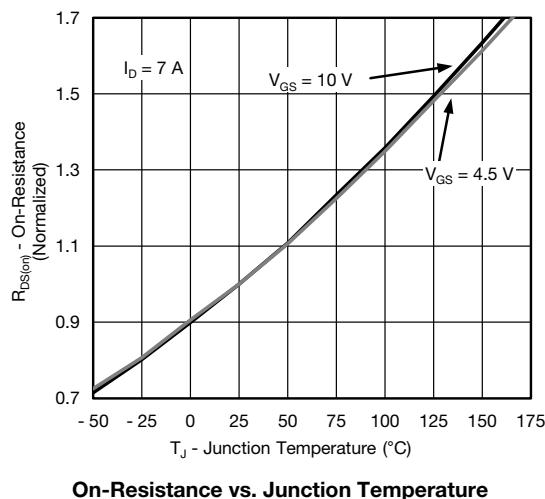
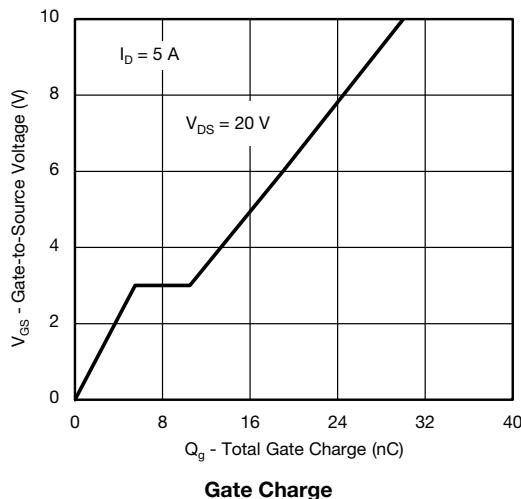
| SPECIFICATIONS ($T_C = 25^\circ\text{C}$, unless otherwise noted) | | | | | | | | |
|----------------------------------------------------------------------------|---------------------|----------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------|------|--------|-----------|---------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT | |
| Static | | | | | | | | |
| Drain-source breakdown voltage | V_{DS} | $V_{GS} = 0\text{ V}$, $I_D = 250\text{ }\mu\text{A}$ | | 40 | - | - | V | |
| Gate-source threshold voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{A}$ | | 1.5 | 2.0 | 2.5 | | |
| Gate-source leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$ | | - | - | ± 100 | nA | |
| Zero gate voltage drain current | I_{DSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 40\text{ V}$ | - | - | 1 | μA | |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = 40\text{ V}$, $T_J = 125^\circ\text{C}$ | - | - | 50 | | |
| | | $V_{GS} = 0\text{ V}$ | $V_{DS} = 40\text{ V}$, $T_J = 175^\circ\text{C}$ | - | - | 150 | | |
| On-state drain current ^a | $I_{D(\text{on})}$ | $V_{GS} = 10\text{ V}$ | $V_{DS} \geq 5\text{ V}$ | 25 | - | - | A | |
| Drain-source on-state resistance ^a | $R_{DS(\text{on})}$ | $V_{GS} = 10\text{ V}$ | $I_D = 7\text{ A}$ | - | 0.0112 | 0.0135 | Ω | |
| | | $V_{GS} = 10\text{ V}$ | $I_D = 7\text{ A}$, $T_J = 125^\circ\text{C}$ | - | - | 0.0198 | | |
| | | $V_{GS} = 10\text{ V}$ | $I_D = 7\text{ A}$, $T_J = 175^\circ\text{C}$ | - | - | 0.0235 | | |
| | | $V_{GS} = 4.5\text{ V}$ | $I_D = 5\text{ A}$ | - | 0.0123 | 0.0148 | | |
| Forward transconductance ^b | g_{fs} | $V_{DS} = 15\text{ V}$, $I_D = 7\text{ A}$ | | - | 30 | - | S | |
| Dynamic^b | | | | | | | | |
| Input capacitance | C_{iss} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 25\text{ V}$, $f = 1\text{ MHz}$ | - | 1760 | 2200 | pF | |
| Output capacitance | C_{oss} | | | - | 252 | 315 | | |
| Reverse transfer capacitance | C_{rss} | | | - | 93 | 116 | | |
| Total gate charge ^c | Q_g | $V_{GS} = 10\text{ V}$ | $V_{DS} = 20\text{ V}$, $I_D = 5\text{ A}$ | - | 30 | 45 | nC | |
| Gate-source charge ^c | Q_{gs} | | | - | 5.5 | - | | |
| Gate-drain charge ^c | Q_{gd} | | | - | 5 | - | | |
| Gate resistance | R_g | $f = 1\text{ MHz}$ | | 2.2 | 4.53 | 6.8 | Ω | |
| Turn-on delay time ^c | $t_{d(\text{on})}$ | $V_{DD} = 20\text{ V}$, $R_L = 4\text{ }\Omega$ $I_D \approx 5\text{ A}$, $V_{GEN} = 10\text{ V}$, $R_g = 1\text{ }\Omega$ | | - | 10 | 15 | ns | |
| Rise Time ^c | t_r | | | - | 40 | 60 | | |
| Turn-Off Delay Time ^c | $t_{d(\text{off})}$ | | | - | 32 | 48 | | |
| Fall time ^c | t_f | | | - | 11 | 17 | | |
| Source-Drain Diode Ratings and Characteristics^b | | | | | | | | |
| Pulsed current ^a | I_{SM} | | | - | - | 32 | A | |
| Forward voltage | V_{SD} | $I_F = 7\text{ A}$, $V_{GS} = 0\text{ V}$ | | - | 0.76 | 1.2 | V | |

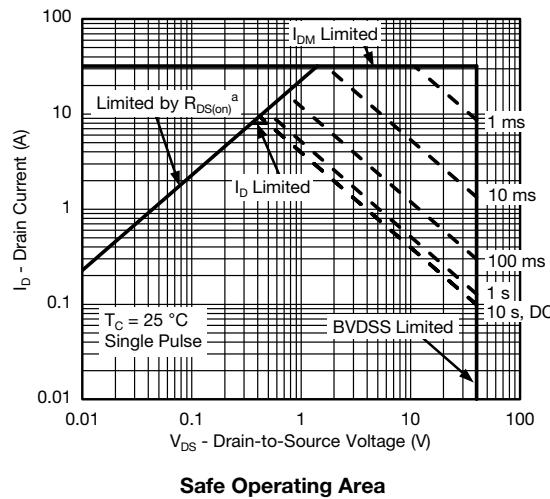
Notes

- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
- Guaranteed by design, not subject to production testing
- Independent of operating temperature

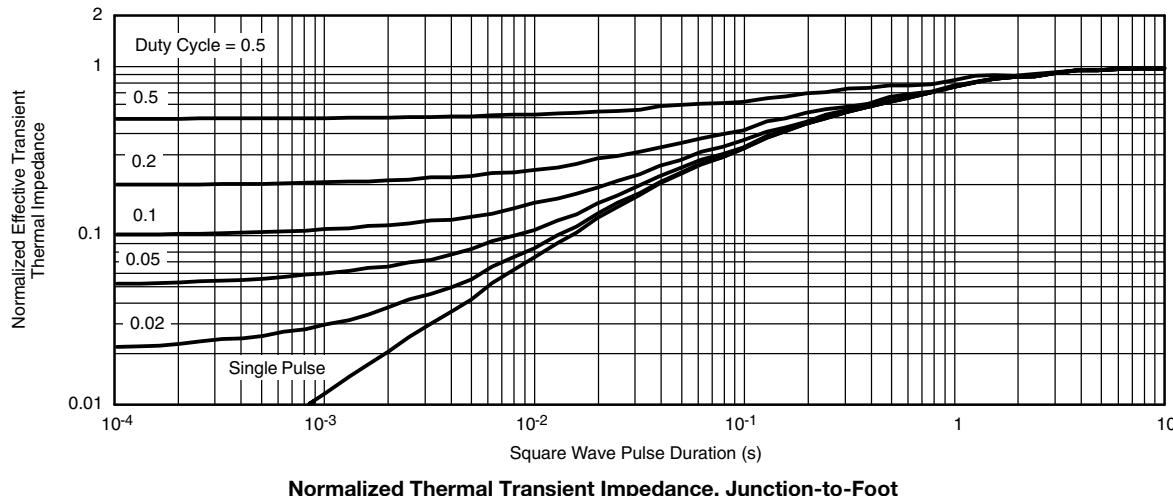
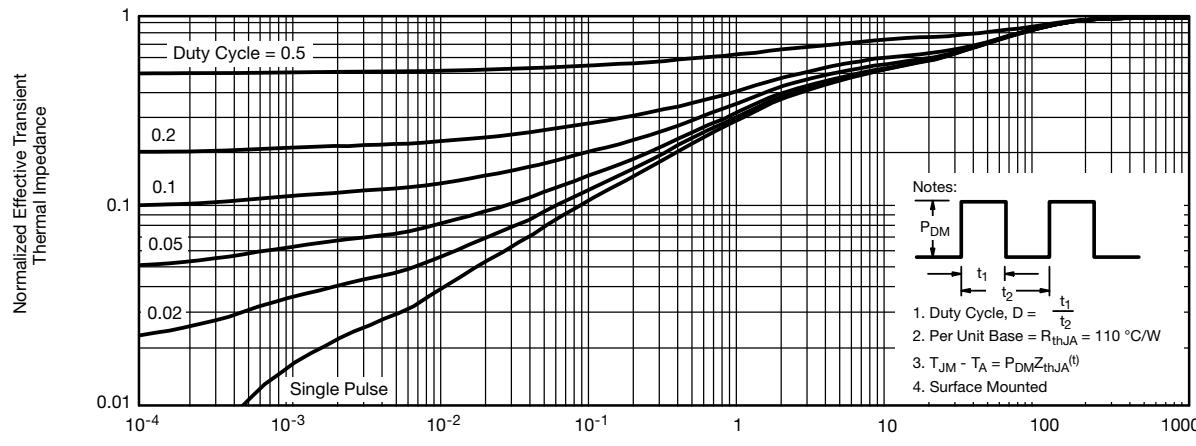
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)


TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)


THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Note

a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Note

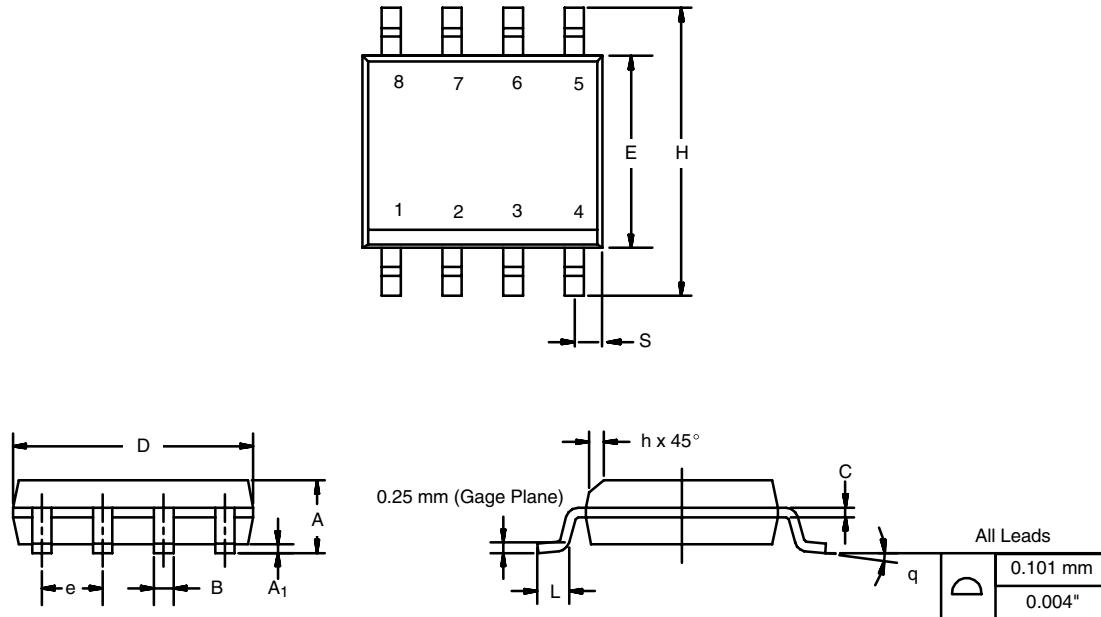
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25°C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25°C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67334.

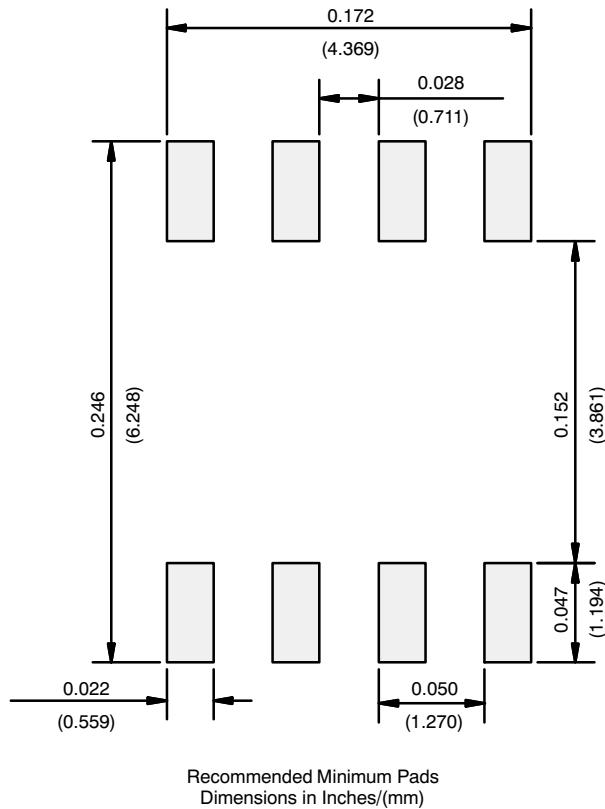
SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012



| DIM | MILLIMETERS | | INCHES | |
|--------------------------------|-------------|------|-----------|-------|
| | Min | Max | Min | Max |
| A | 1.35 | 1.75 | 0.053 | 0.069 |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 |
| B | 0.35 | 0.51 | 0.014 | 0.020 |
| C | 0.19 | 0.25 | 0.0075 | 0.010 |
| D | 4.80 | 5.00 | 0.189 | 0.196 |
| E | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| H | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.020 |
| L | 0.50 | 0.93 | 0.020 | 0.037 |
| q | 0° | 8° | 0° | 8° |
| S | 0.44 | 0.64 | 0.018 | 0.026 |
| ECN: C-06527-Rev. I, 11-Sep-06 | | | | |
| DWG: 5498 | | | | |

RECOMMENDED MINIMUM PADS FOR SO-8



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